

Rectifier diode fast, high-voltage

BY459F-1500

GENERAL DESCRIPTION

Glass-passivated double diffused rectifier diode in a full pack plastic envelope, featuring fast forward recovery and low forward recovery voltage. The device is intended for use in multi-sync monitor deflection circuits up to 82kHz.

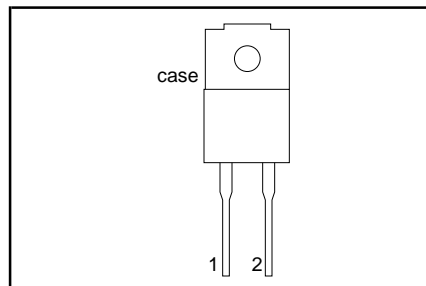
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V_{RRM}	Repetitive peak reverse voltage	1500	V
V_F	Forward voltage	1.2	V
$I_{F(AV)}$	Average forward current	10	A
I_{FSM}	Non-repetitive peak forward current	100	A
t_{fr}	Forward recovery time	250	ns
V_{fr}	Forward recovery voltage	14	V

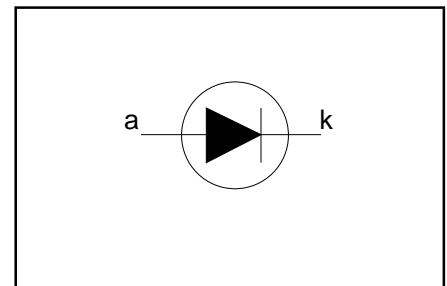
PINNING - SOD100

PIN	DESCRIPTION
1	cathode
2	anode
case	isolated

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RSM}	Non repetitive peak reverse voltage		-	1500	V
V_{RRM}	Repetitive peak reverse voltage		-	1500	V
V_{RWM}	Crest working reverse voltage		-	1300	V
$I_{F(AV)}$	Average forward current	sinusoidal; $T_{hs} \leq 68^\circ\text{C}$	-	10	A
$I_{F(RMS)}$	RMS forward current		-	15.7	A
I_{FRM}	Repetitive peak forward current	sinusoidal; $a = 1.57$	-	100	A
I_{FSM}	Non repetitive peak forward current	$t = 10\text{ ms}$	-	100	A
		$t = 8.3\text{ ms}$	-	110	A
		sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge; with reapplied $V_{RWM(max)}$	-		
I^2t	I^2t for fusing	$t = 10\text{ ms}$	-	50	A^2s
T_{stg}	Storage temperature		-40	150	$^\circ\text{C}$
T_j	Operating junction temperature		-	150	$^\circ\text{C}$

ISOLATION

$T_{hs} = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	Repetitive peak voltage from both terminals to external heatsink	R.H. $\leq 65\%$; clean and dustfree	-	-	1500	V
C_{isol}	Capacitance from cathode to external heatsink	$f = 1\text{ MHz}$	-	12	-	pF

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-hs}$	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.8	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	without heatsink compound in free air	-	55	5.9	K/W
			-		-	K/W

STATIC CHARACTERISTICS $T_j = 25\text{ °C}$ unless otherwise stated

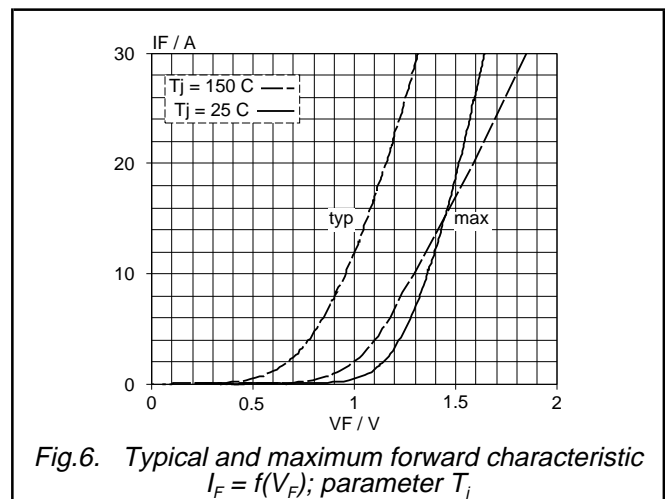
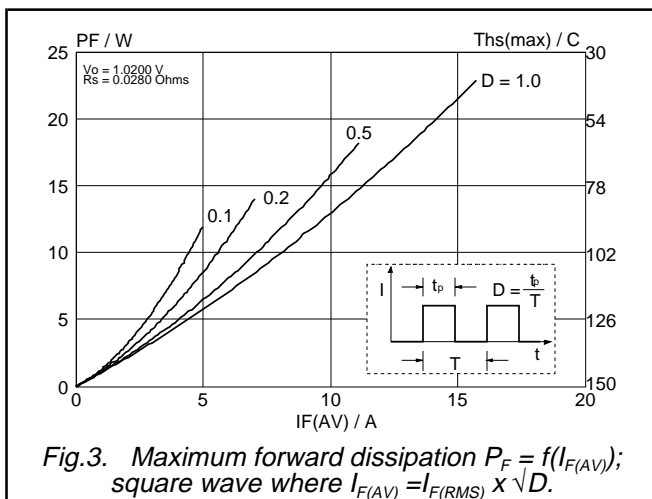
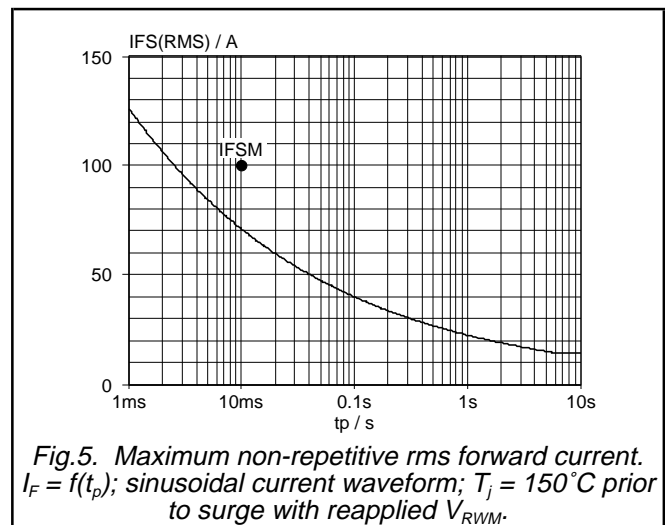
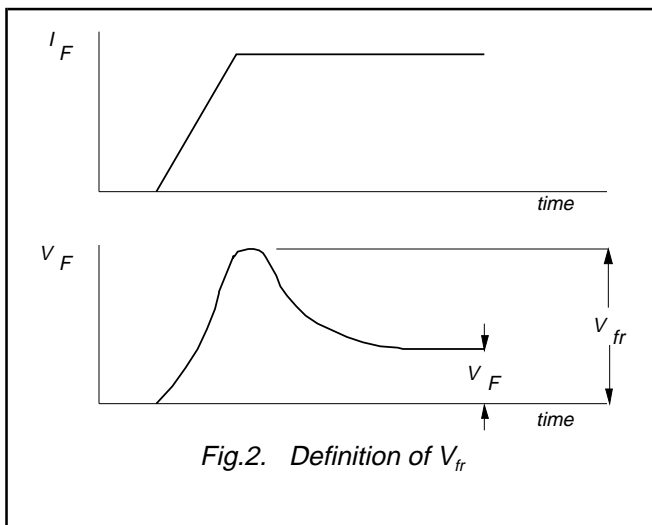
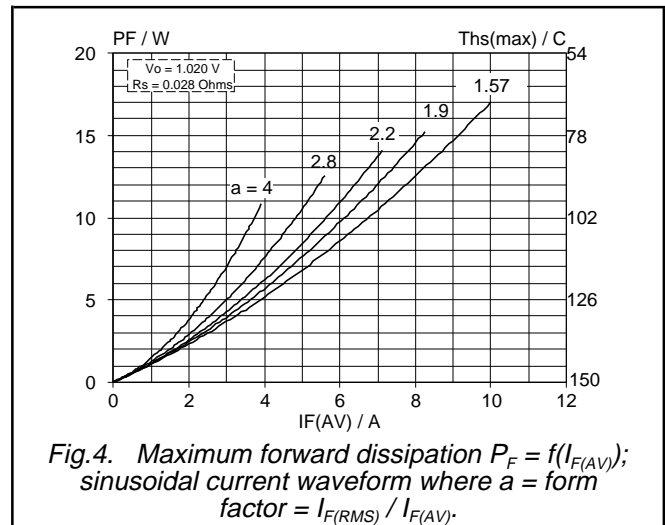
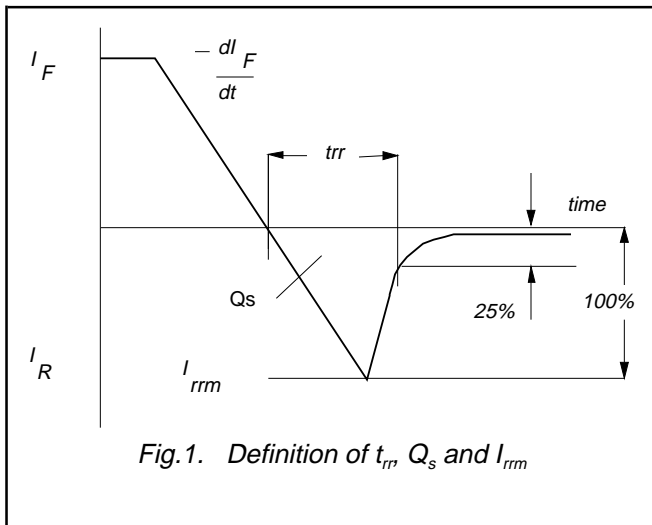
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 6.5\text{ A}$	-	0.95	1.3	V
I_R	Reverse current	$I_F = 6.5\text{ A}; T_j = 125\text{ °C}$	-	0.85	1.2	V
		$V_R = V_{RWMmax}$	-	-	0.25	mA
		$V_R = V_{RWMmax}; T_j = 125\text{ °C}$	-	-	1.0	mA

DYNAMIC CHARACTERISTICS $T_j = 25\text{ °C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{fr}	Forward recovery voltage	$I_F = 6.5\text{ A}; di_F/dt = 50\text{ A}/\mu\text{s}$	-	8	14	V
t_{fr}	Forward recovery time	$I_F = 6.5\text{ A}; di_F/dt = 50\text{ A}/\mu\text{s}; V_F = 5\text{ V}$	-	170	250	ns
		$I_F = 6.5\text{ A}; di_F/dt = 50\text{ A}/\mu\text{s}; V_F = 2\text{ V}$	-	350	-	ns
t_{rr}	Reverse recovery time	$I_F = 1\text{ A}; -di_F/dt = 50\text{ A}/\mu\text{s}; V_R \geq 30\text{ V}$	-	250	350	ns

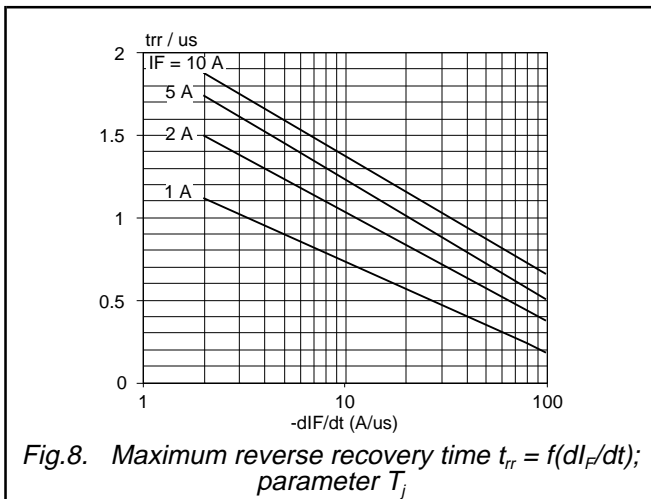
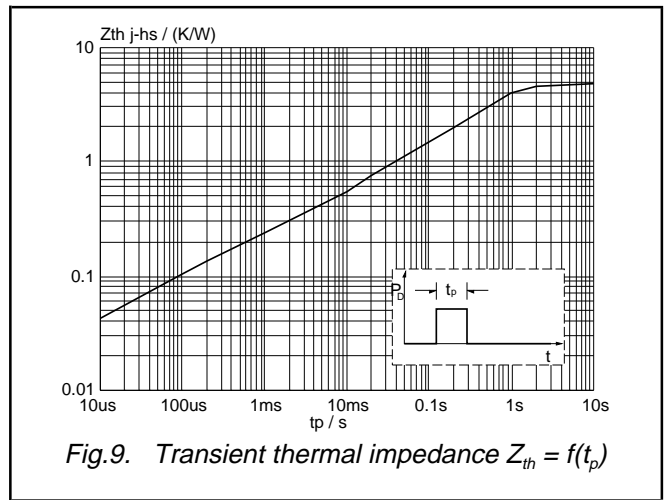
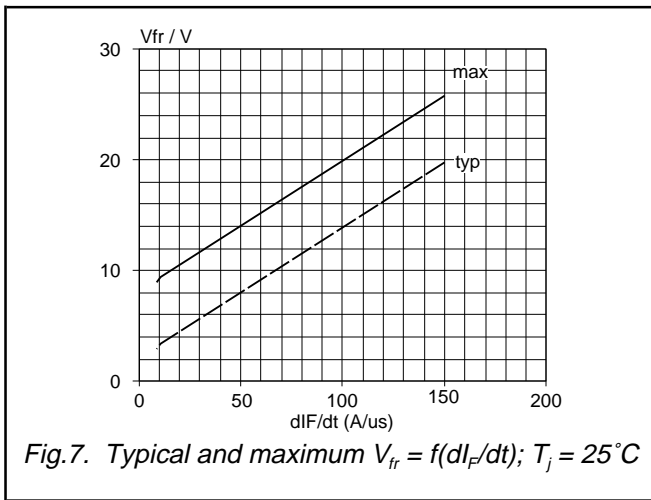
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MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

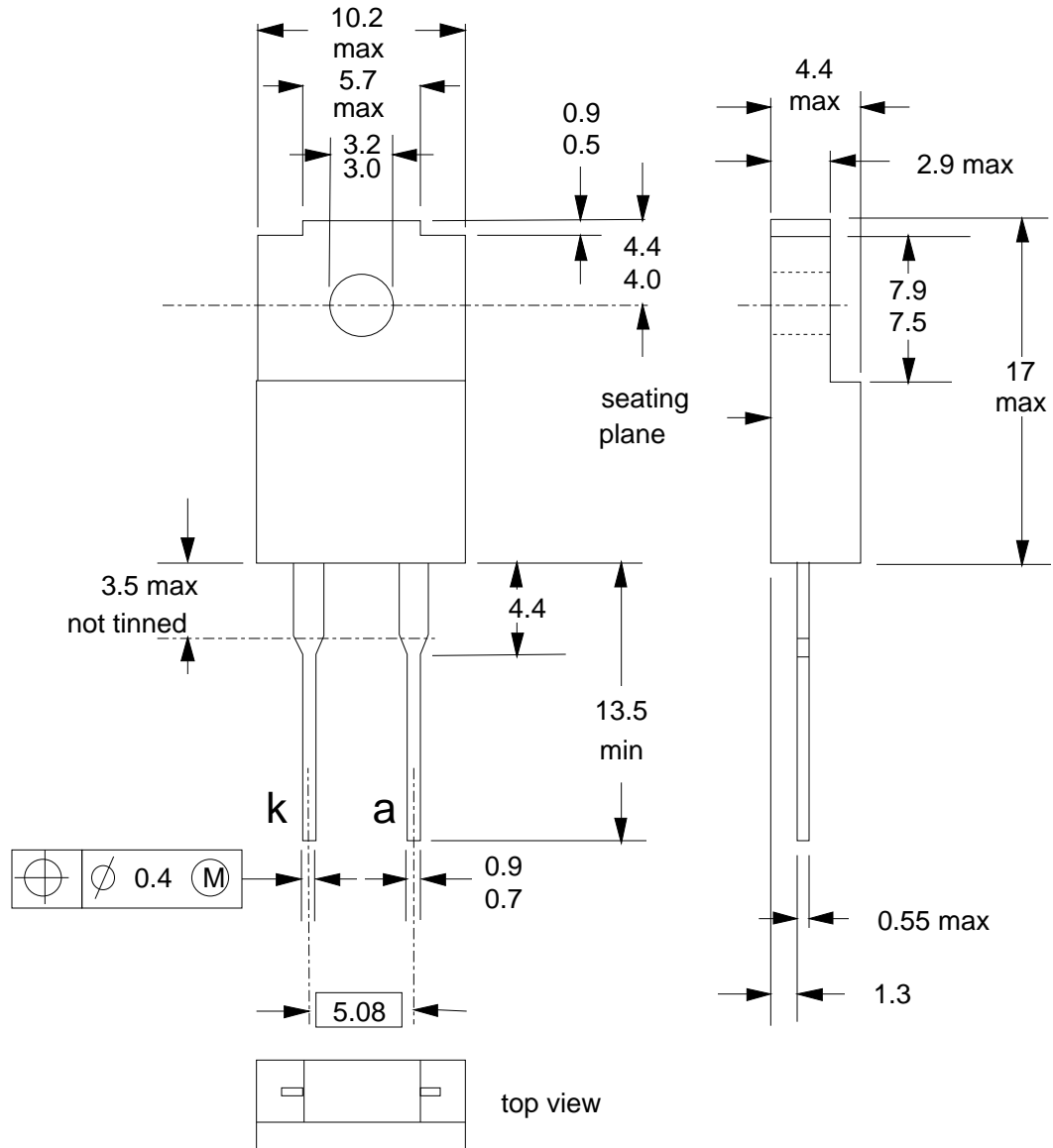


Fig. 10. SOD100; The seating plane is electrically isolated from all terminals.

Notes

- 1. Accessories supplied on request: refer to mounting instructions for F-pack envelopes.
- 2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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